

60 V, 10 A NPN high power bipolar transistor 27 May 2015

Product data sheet

1. General description

NPN high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

PNP complement: PHPT60610PY

2. Features and benefits

- High thermal power dissipation capability
- High temperature applications up to 175 °C
- Reduced Printed Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation
- AEC-Q101 qualified.

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Motor drive
- Relay replacement

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	60	V
I _C	collector current			-	-	10	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	20	А
R _{CEsat}	collector-emitter saturation resistance	$\begin{split} I_C &= 10 \text{ A}; I_B = 1 \text{ A}; \text{ pulsed}; t_p \leq 300 \mu\text{s}; \\ \delta &\leq 0.02 ; T_{amb} = 25 ^\circ\text{C} \end{split}$		-	25	36	mΩ



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter	mb	С
2	Е	emitter		в
3	Е	emitter	q	- h a
4	В	base	មិតតត្	E sym123
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	Syn1123

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PHPT60610NY	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT60610NY	0610NAB

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	60	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
I _C	collector current			-	10	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	20	А
I _B	base current			-	1.5	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	2	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.5	W
			[2]	-	3.7	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

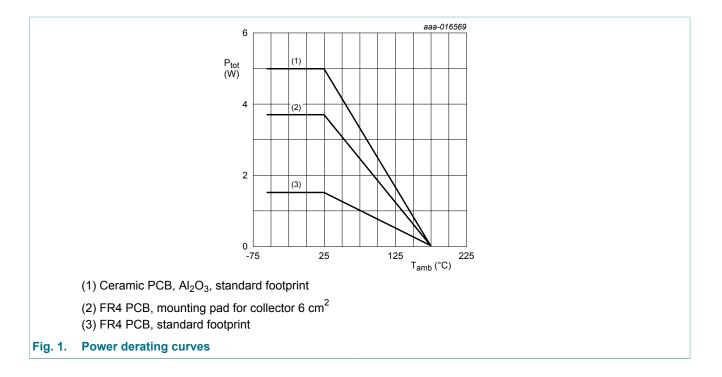
[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated and mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB; AI_2O_3 , standard footprint.

[4] Power dissipation from junction to mounting base.

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9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1]	-	-	100	K/W
		[2]	-	-	41	K/W	
	unbient		[3]	-	-	30	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	-	6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

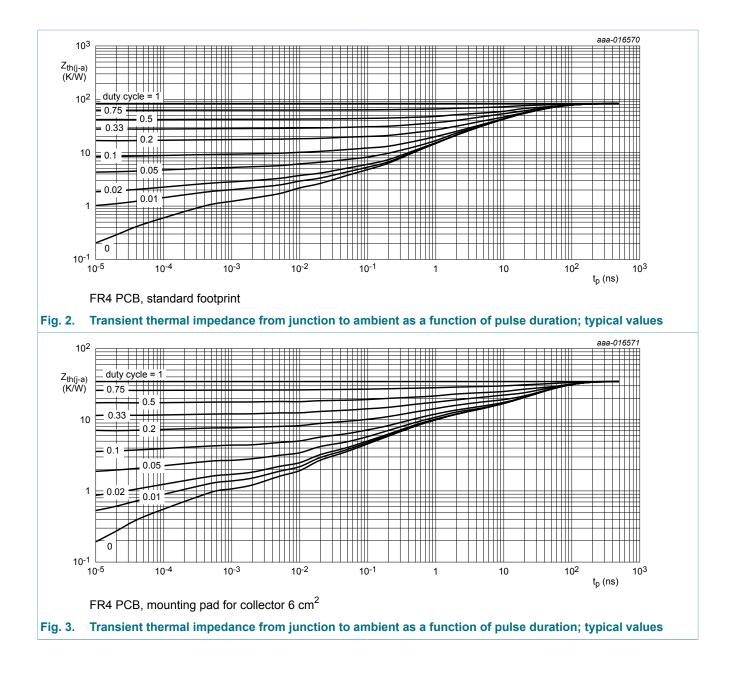
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².

[3] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

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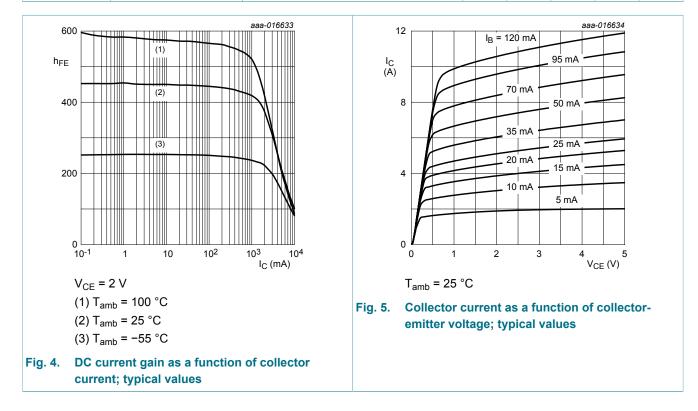
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = 48 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 48 V; I _E = 0 A; T _j = 150 °C	-	-	50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = 48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = 7 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	240	410	-	
		$V_{CE} = 2 \text{ V; } I_C = 1 \text{ A; } t_p \le 300 \mu\text{s;}$ $\delta \le 0.02 \text{ ; } T_{amb} = 25 ^\circ\text{C}$	210	400	-	
		$V_{CE} = 2 \text{ V; } I_C = 5 \text{ A; } t_p \le 300 \mu\text{s;}$ $\delta \le 0.02 \text{ ; } T_{amb} = 25 ^\circ\text{C}$	100	200	-	
		$V_{CE} = 2 \text{ V; } I_C = 10 \text{ A; } t_p \le 300 \mu\text{s;}$ $\delta \le 0.02 \text{ ; } T_{amb} = 25 \text{ °C; pulsed}$	50	100	-	
olout	collector-emitter saturation voltage	$\begin{split} I_C = 1 \text{ A}; \ I_B = 50 \text{ mA}; \ t_p \leq 300 \mu\text{s}; \\ \delta \leq 0.02 \ ; \ T_{amb} = 25 \ ^\circ\text{C}; \ \text{pulsed} \end{split}$	-	30	40	mV
		$\begin{split} I_C &= 5 \text{ A}; I_B = 500 \text{ mA}; \text{ pulsed}; \\ t_p &\leq 300 \mu\text{s}; \delta \leq 0.02 ; T_{\text{amb}} = 25 ^\circ\text{C} \end{split}$	-	115	160	mV
		I_{C} = 10 A; I_{B} = 1 A; pulsed; $t_{p} \le 300 \ \mu s$;	-	250	360	mV
R _{CEsat}	collector-emitter saturation resistance	$\delta \le 0.02$; T _{amb} = 25 °C	-	25	36	mΩ
V _{BEsat}	base-emitter saturation voltage	$\begin{split} I_{C} &= 1 \text{ A}; I_{B} = 50 \text{ mA}; \text{ pulsed}; \\ t_{p} &\leq 300 \mu\text{s}; \delta \leq 0.02 ; T_{amb} = 25 ^{\circ}\text{C} \end{split}$	-	-	0.95	V
		$\begin{split} I_{C} &= 5 \text{ A}; I_{B} = 500 \text{ mA}; \text{ pulsed}; \\ t_{p} &\leq 300 \mu\text{s}; \delta \leq 0.02 ; T_{amb} = 25 ^{\circ}\text{C} \end{split}$	-	-	1.2	V
		I_C = 10 A; I_B = 1 A; pulsed; $t_p \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-	1.4	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	-	-	0.8	V
t _d	delay time	V_{CC} = 12.5 V; I _C = 5 A; I _{Bon} = 250 mA;	-	20	-	ns
t _r	rise time	I_{Boff} = -250 mA; T_{amb} = 25 °C	-	180	-	ns
t _{on}	turn-on time	=	-	200	-	ns
t _s	storage time		-	340	-	ns
t _f	fall time		-	165	-	ns
t _{off}	turn-off time		-	505	-	ns

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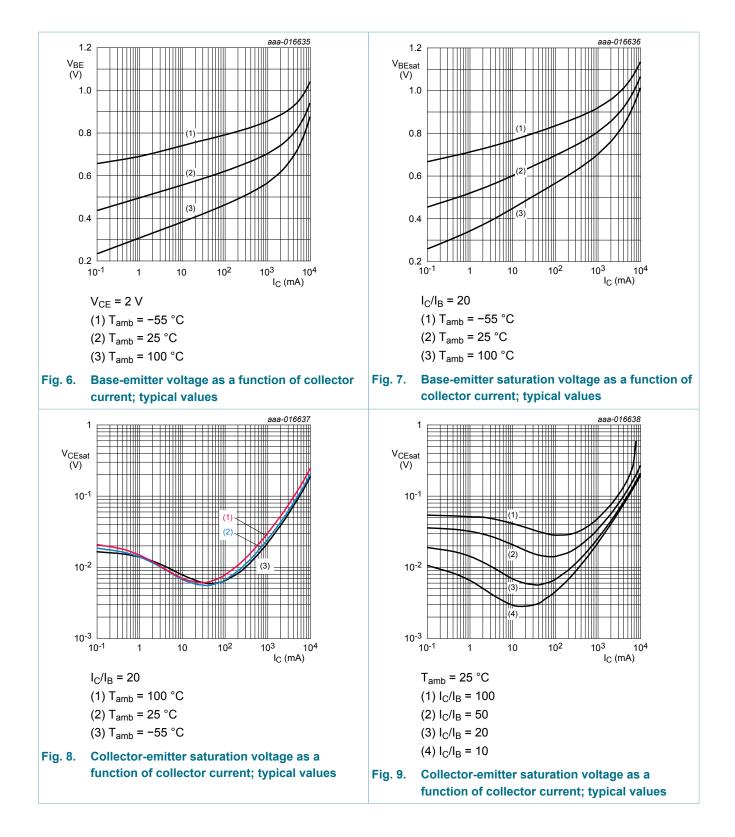
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _T	transition frequency	V_{CE} = 10 V; I _C = 500 mA; f = 100 MHz; T _{amb} = 25 °C	-	140	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	50	-	pF



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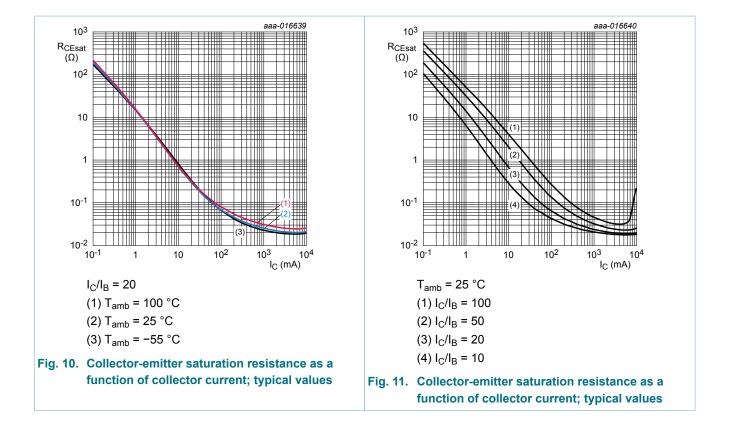
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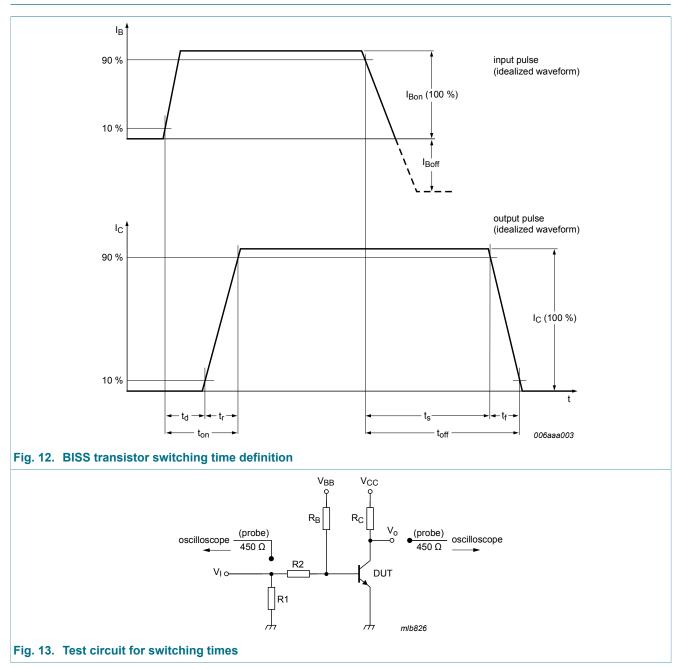
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11. Test information

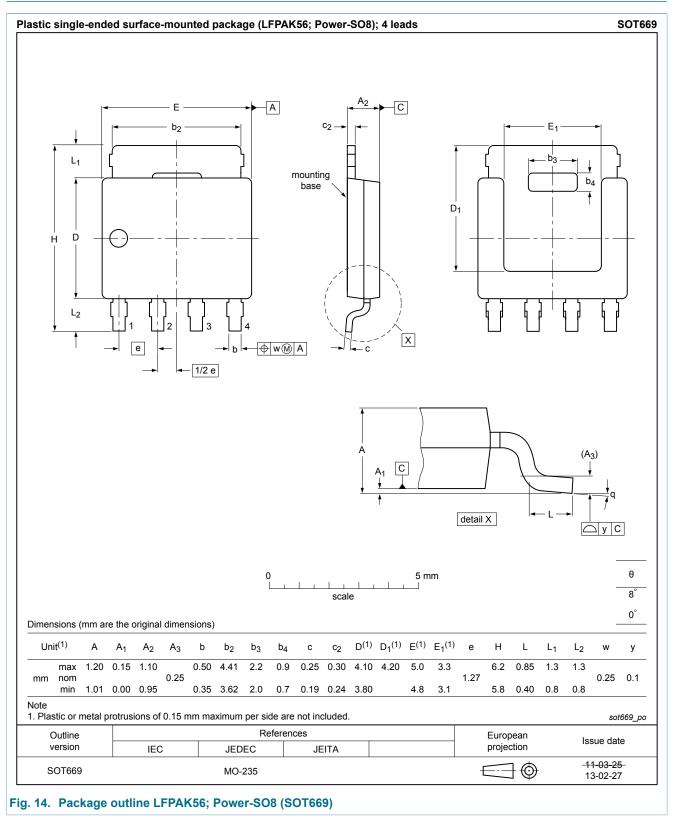


This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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12. Package outline



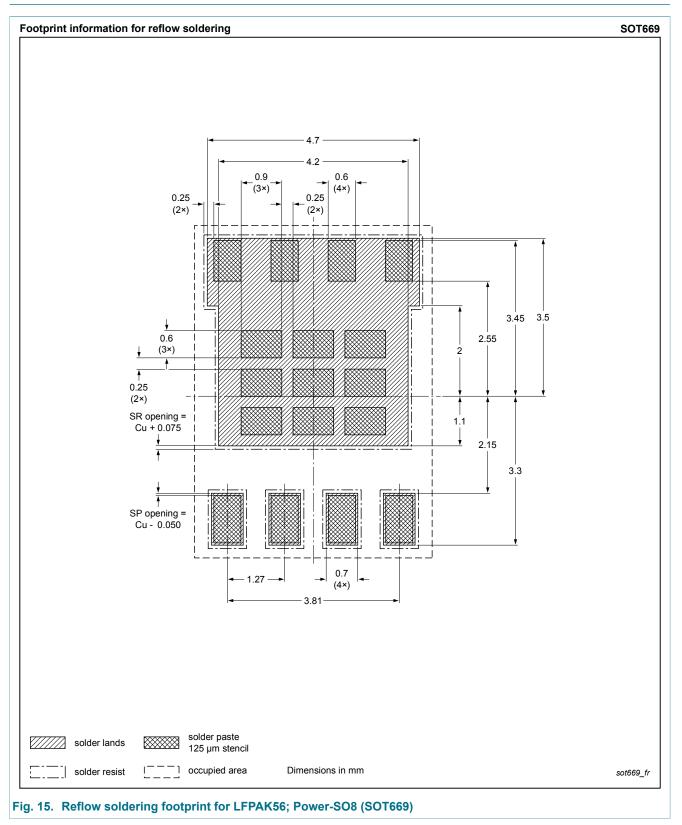
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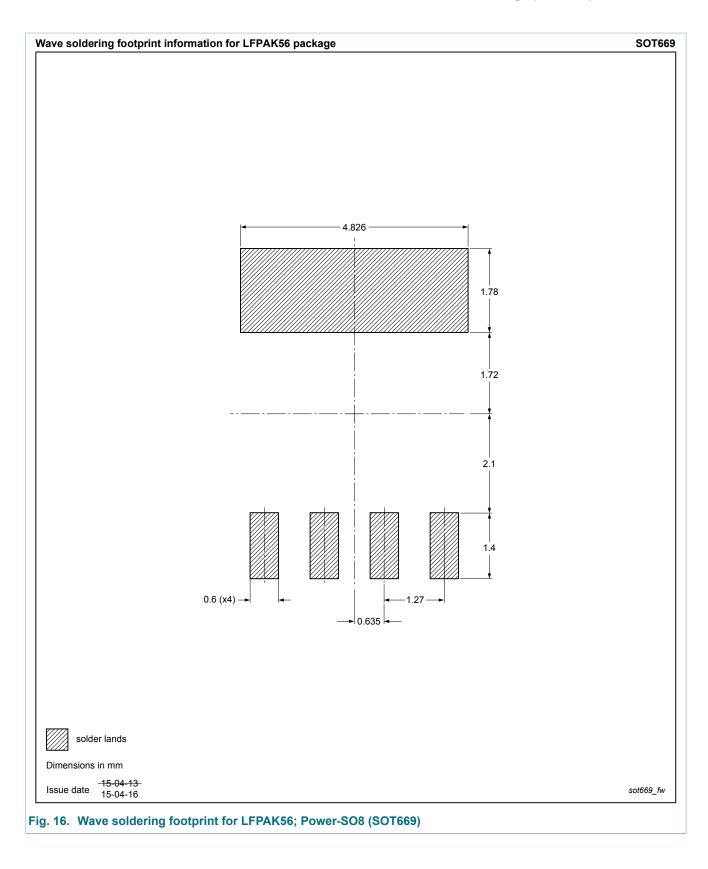
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13. Soldering



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14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT60610NY v.1	20150527	Product data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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